Im portance of individual scattering m atrix elements at Fano resonances

P. Singha Deo

S.N.Bose National Centre for Basic Sciences, JD Block, Sector III, Salt Lake City, Kolkata 98, India.

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Single particle resonances in quantum wires are generally Fano resonances. In case of Fano resonances, the scattering phase shift in som e channels show sharp phase drops and that in the other channels do not. Phase shift in a particular channel can be measured and can yield inform ation about the integrated charge localized around the scatterer. This paper tries to analyze if som e channels are more inform ative than the others, so that an experimentalist can measure the phase shift in only those channels.

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I. IN TRODUCTION

M iniaturization of devices is an ever pressing dem and. It is also obvious that to sustain m iniaturization, we have to use system s that are so sm all that the laws of physics is determ ined by Q uantum M echanics. So understanding the properties of so called m esoscopic system s is also very dem anding [1]. C incuits of future devices w ill be m ade up of quantum w ires. Junctions in such circuits also has to be understood from Q uantum m echanics. Such a sim ple junction is what is referred to as a three prong potential [2] and it is schem atically shown in Fig. 1. There are several papers that explore the importance of such a junction in a m esoscopic system [3, 4].

W hile bound states are in portant to understand the therm odynam ic properties of a sam ple [5], the scattering states are in portant to understand the transport properties [6]. How ever, it is not always necessary to solve the bound states and the scattering states separately. Both these states are solutions of the same H am iltonian but with di erent boundary conditions. It is possible to solve only the scattering states and thereby also understand the bound states as an analytical continuation of the scattering states. At the heart of this principle is the Friedel sum rule [7, 8] that states that for non-polarizable leads [7]

$$\frac{d_{f}}{dE} \quad [(E)_{0}(E)] \qquad (1)$$

The correction term s are sm all in W KB regime [7]. Here

$$f = \frac{d}{dE} \frac{1}{2i} \log D \text{ et [S]}; \qquad (2)$$

E is the incident electron energy, S is the scattering matrix, (E) is the density of states (DOS) at energy E in presence of scattering, $_0$ (E) is DOS in absence of scattering. f is referred to as the Friedel phase. The RHS of Eq. 1 is therefore related to the integrated charge localized around the scatterer and this can be determined from the S matrix.

A number of experiments [9, 10, 11] show that the phase of a particular scattering matrix element can be m easured. Yeyati and Buttiker [12] rst proposed that such phases can be understood from the Friedel sum rule (FSR). It was later found that transm ission zeroes play a special role $[\beta, 13, 14]$ and change our understanding of the FSR.

II. THE PROBLEM

N orm ally, in m esoscopic system s, S is a large but nite m atrix, and often all the m atrix elements are not completely independent. So, it may not be necessary to evaluate all the elements of S, in order to calculate $_{\rm f}$. M oreover, in m esoscopic system s, it is possible to m easure a particular m atrix element of S. O ne can m easure the phase as well as the amplitude of the m atrix element [9]. For a large dimensional S m atrix, it may not be possible to m easure all the elements of S. So, it is important to know what kind of physical inform atrix element and which are the important m atrix elements. For example, in case of a one dimension (1D) system, the scattering m atrix is 2x2, and [15]

$$\frac{d}{dE} \arg (T) = \frac{d_{f}}{dE}$$
(3)

where T is the transmission amplitude and arg(T) = $A \operatorname{rctan} \frac{\operatorname{Im} [T]}{\operatorname{Re}[T]}$. Situation is complicated in quasi-1D where a single transverse mode is populated and the scattering matrix is 2x2. This is because of the presence of discontinuous changes in scattering phase shifts at Fano resonances [3]. For such system s it was shown [8]

$$\frac{\mathrm{d}}{\mathrm{dE}} \arg(\mathbf{T}) = \frac{\mathrm{d}_{\mathrm{f}}}{\mathrm{dE}} \qquad (\mathbf{E} \quad \mathbf{E}_{0}) \tag{4}$$

Here, E_0 is the Ferm i energy at which T = 0. T = 0 occur because of Fano resonance and is a general feature of quasi-1D [14]. Situation is further complicated in multichannel quasi-1D where the dimensionality of S matrix is more than 2x2. In case of a multichannel Fano resonance, there are sharp continuous phase drops at the minim a of certain scattering probabilities, while not so for others [7]. For example, in case of the function potential in a multichannel quantum wire, there are sharp

drops in arg ($T_{m\,m}$) versus incident energy, when $J_{m\,m} \stackrel{2}{\rightarrow} ism$ in in um. But, this does not happen for arg ($T_{m\,n}$) or arg ($R_{m\,n}$) or arg ($R_{m\,m}$). There it was shown [7]

$$\frac{d}{dE} \arg(R_{mn}) = \frac{d}{dE} \arg(R_{mm}) = \frac{d}{dE} \arg(T_{mn}) = \frac{d}{dE} \frac{d}{dE}$$
(5)

where m \Leftrightarrow n, R_{mn} is rejection amplitude from m th transverse channel to nth transverse channel, R_{mm} is re-

ection am plitude from m th transverse channel to m th transverse channel and $T_{m\,n}$ is transm ission am plitude from m th transverse channel to nth transverse channel. Eq. 5 also applies to the potentials studied in Ref. [8] but eq. 4 does not apply to the multi channel wire with a function potential.

W hich m eans charge transfer is determ ined by the energy derivatives of those arg (S $\,$) that do not show a drop. Their derivatives are identical to the derivatives of the Friedel phase $_{\rm f}$. However, delta function potential, as well as the potentials studied in Ref. [8] are all point scatterers and it is not known if this feature is general. This motivates us to study an extended potential that can exhibit multi channel Fano resonance.

So in this paper we study the system shown in Fig. 1, as it is an extended potential. W e shall show that it can exhibit multichannel Fano resonance. It is a simple m odel, that allows analytical understanding and allows us to check if the S m atrix elements whose phase do not show a negative slope carry the information about the DOS.Besides, the potential considered here has certain subtleties. A di erent kind of subtlety exists [] for a potential in quasi-1D, namely there is an exponentially decaying local density of states (LDOS) in the leads due to the evanescent modes. One has to be careful about interpreting what is a non-polarizable lead that norm ally m eans that the integrated LDOS in the leads are not be considered in (1). But in quasi 1D it is not possible to separate the LDOS in the leads and the LDOS in the sample. The exponentially decaying LDOS in the leads are to be included in (1) but the non-decaying LDOS in the leads should not be included in (1) [7]. As a result, the correction terms to Eq. (1) are negligible in WKB regim e is no longer a correct statem ent [7]. In the present case, the subtlety arises with the interpretation of $_0$ as will be explained in section IV.

III. THE SCATTER ING SOLUTION

C onsider the geom etry, schem atically shown in Fig. 1. The thin lines are sem i-in nite 1D quantum wires (that successfully models a quasi 1D quantum wire with a single transverse mode populated) with quantum mechanical potential V = 0, while the thick lines are quantum wires with a potential $V \notin 0$. An incident electron is shown by the arrow head and the quantum mechanical wave functions in the di erent regions I, II, III, IV, V and VI are written below.

$$I = e^{ik(x - l_1)} + R_{11}e^{-ik(x - l_1)}$$
(6)

$$_{II} = A e^{iqx} + B e^{-iqx}$$
(7)

$$III = C e^{iqy} + D e^{iqy}$$
(8)

$$_{\rm IV} = F e^{iqz} + G e^{-iqz}$$
(9)

$$v = T_{13}e^{ik(z - l_3)}$$
 (10)

$$v_{I} = T_{12} e^{ik(y - l_2)}$$
 (11)

 l_1 , l_2 and l_3 are de ned in Fig. 1. These wave functions have to be continuous and current has to be conserved at the junctions. From this we get a set 9 linear equations from which we can solve the 9 unknown coe cients that are A; B; C; D; F; G; R₁₁; T₁₂ and T₁₃. Sim ilarly, we have to solve the scattering problem when the incident electron is from the top, in order to obtain R₂₂; T₂₁ etc. Thus we can determ ine the scattering matrix. It is a three channel problem and the scattering matrix is 3x3 as shown below.

$$S = \begin{pmatrix} 0 & & 1 \\ R_{11} & T_{12} & T_{13} \\ T_{21} & R_{22} & T_{23} \\ T_{31} & T_{32} & R_{33} \end{pmatrix}$$
(12)

It is known that [1]

(E) =
$$\frac{1}{2}$$
 Im Tr[G^{ret}(r;r⁰;E)] =

X
$$Z_{1}$$

(E $E_{k;1}$) $drj_{k;1}(r)j = (W)(E) + k;1$

$$\frac{2}{hv} \int_{1}^{Z} \frac{1}{hv} dx + \frac{2}{hv} \int_{1}^{Z} \frac{1}{hv} dy + \frac{2}{hv} \int_{1}^{Z} \frac{1}{hv} dz +$$

$$\frac{2\Re_{11}j^{Z_{1}}}{hv} \int_{1}^{Z_{1}} \cos(2kx + 1) dx + \frac{2\Re_{22}j^{Z_{12}}}{hv} \int_{1}^{Z_{12}} \cos(2ky + 2) dy$$

$$+\frac{2\Re_{33}j}{hv}\int_{1}^{z} \cos(2kz+3)dz \qquad (13)$$

Here $G^{ret}(r; r^0; E)$ is the retarded G reen's function and $(M^{\circ})(E)$ is the integrated local DOS in the thick region

(18)

of Fig. 1. A llow ed modes in the system are denoted by m om entum index k = ^{2m}/₂ (E V) and l can take three values (1, 2 and 3), corresponding to incident electron from three possible directions. Here m is electronic mass and v is $\frac{-k}{m}$. $_1 = \arg(R_{11})$ and so on. Here

$$^{(W)}(E) = {}^{(W)}_{1}(E) + {}^{(W)}_{2}(E) + {}^{(W)}_{3}(E) = {}^{X}_{1}(E)$$

$$(14)$$

where

$$\binom{W}{1}$$
 (E) = $\frac{1}{hv} \begin{bmatrix} Z & 0 \\ 1 & A e^{iqx} + B e^{-iqx} \int dx + B e^{-iqx} \int$

$$\begin{bmatrix} Z \\ 1_2 \end{bmatrix} \begin{bmatrix} Z \\ 1_3 \end{bmatrix} \begin{bmatrix} z \\ z \end{bmatrix}$$

That is $\binom{(W)}{1}$ (E) is calculated with the incident electron from the left. $\binom{(W)}{2}$ (E) is calculated with the incident electron from the top. And $\frac{(W)}{3}$ (E) is calculated with the incident electron from the right. Substituting eq. 13 in eq. 1 and considering the mesoscopic leads to be unpolarizable (W hich m eans the last 3 term s on the R H S of eq. 13 are to be ignored. A ctually even if one does not want to invoke the non-polarizability of the leads, one can evaluate those inde nite integrals and see that these term s are negligibly sm all in the regime of interest, which is the W KB regime. This is the regime where transport occurs) we get

$$\frac{\mathrm{d}_{\mathrm{f}}}{\mathrm{d}\mathrm{E}} \begin{bmatrix} {}^{\mathrm{(W)}} (\mathrm{E}) & {}^{\mathrm{(W)}}_{0} (\mathrm{E}) \end{bmatrix}$$
(16)

IV. ELIMINATION OF
$$_{0}^{(W)}$$
 (E)

In case of the three prong potential, it is not possible to realize the state of \absence of scattering". Even if we make the potential V in Fig. 1, equal to 0, we get $T_{12} = T_{13} = 2=3$ and $R_{11} = 1=3$ for $l_1 = l_2 = l_3$. Even for unequal $\frac{1}{2}$, $\frac{1}{2}$ and $\frac{1}{2}$, there is always some re ection and scattering, in absence of the potential. This is often encountered in case of scattering by topological defects where there is no continuous way of going to the defect free regime. So rst we have to eliminate $_{0}^{(W)}$ (E), i.e., the DOS in absence of scattering. This is dealt with in this section.

O ne can say that when V = 0, then

$$\frac{d f}{dE} \begin{bmatrix} (W^{0}) (E) & (W^{0}) (E) \end{bmatrix}$$
(17)

Here, W^{0} stands for the thick region in Fig. I with V set to 0. ⁰ is calculated from the S matrix when V = 0. $\int_{0}^{(\!W\!)}$ (E) is the DOS of the unknown system , that is the

defect free version of the scattering system being studied. V = 0 situation yields a S m atrix given below.

$$\begin{array}{c} 0 \\ (1=3)e^{2ik\,l_1} \\ S^0 = \begin{pmatrix} 0 \\ (2=3)e^{2ik\,l_2} \\ (2=3)e^{2ik\,l_1} \\ (2=3)e^{2ik\,l_2} \\ (2=3)e^{2ik\,l_2} \\ (2=3)e^{2ik\,l_2} \\ (2=3)e^{2ik\,l_2} \\ (2=3)e^{2ik\,l_2} \\ (1=3)e^{2ik\,l_3} \\ \end{array} \begin{array}{c} 1 \\ (2=3)e^{2ik\,l_2} \\ (1=3)e^{2ik\,l_3} \\ (1=3)e^{2ik\,l_3} \\ \end{array}$$

From this it can be proved that

$$\frac{d}{dE} = \frac{d}{dE} \left(\frac{1}{2i} \log D \operatorname{et}[S^0] \right) = \frac{2l_1}{hv} + \frac{2l_2}{hv} + \frac{2l_3}{hv} \qquad (W^{0}) (E)$$
(19)

Sim ilarly, when $V \in 0$,

$$\frac{\mathrm{d}_{\mathrm{f}}}{\mathrm{d}\mathrm{E}} \quad \begin{bmatrix} (W^{\mathrm{o}}) (\mathrm{E}) & 0 \end{bmatrix} \quad (20)$$

From 17 and 20, we nd that

d

$$\frac{d_{f}}{dE} = \frac{d_{f}^{0}}{dE} \qquad [(W) (E) (W^{0}) (E)] \qquad (21)$$

Thus using 19 we get

$$\frac{d_{f}}{dE} \qquad (W)(E) \qquad (22)$$

Οr

$$\frac{d_{f}}{dk} \sim v^{(W)}(k)$$
(23)

W ith the choice of wavefunctions in (6) - (11), this is also what we get for potential scattering. This is because the S-m atrix elements of the three prong potential for V ! 0, does not have any non-trivial energy dependence (energy dependence is same as that of a free particle). But this method of elim ination can be applied to complicated junctions where we will get situations not encountered with potential scattering.

V. RESULTS AND DISCUSSIONS

We rst show that the three prong potential can exhibit multichannel Fano resonance. In Fig. 2, we show that arg(T_{13}) drops sharply when $\int T_{13} f$ m in in izes. In Fig. 3, we show that arg (\mathbb{R}_{11}) drops sharply when $\frac{1}{2}\mathbb{R}_{11}^2$ m in im izes. These are typical signatures of Fano resonances [7]. These phase drops can be sharper than any scale present in the system as shown in Figs. 2 and 3. These phase shifts can be detected experim entally and it is important to investigate the physical inform ations that can be obtained from such phase shifts. In the follow ing we will show that arg (T_{12}) does not show any drop and also calculate the DOS explicitly to check if DOS or Friedel phase is related to $\arg(T_{12})$. Our previous experience, as discussed in section II, suggests that this could be the case.

In Fig. 4, we plot $\frac{d}{d(kl)}$ arg(T₁₂) as a function of kl. It shows sharp peaks and is positive everywhere, im plying

that unlike in arg(T₁₃) or arg(R₁₁), there are no drops or negative slopes in arg(T₁₂). A lso $\frac{d}{d(k_1)}$ arg(T₁₂) is very close to $\frac{d}{d(k_1)}$ and $\sim v^{(W)}$ (kl). Here l is taken to be the unit of length. However, unlike the case of the function potential in Q 1D, $\frac{d}{d(k_1)}$ arg(T₁₂) is not identical to $\frac{d}{d(k_1)}$. They are indeed very close to each other and identical for practical purposes when the Fano resonances are long lived. How ever, for Fano resonances with short life tim es, there are quantitative di erences, although there is qualitative sim ilarity, as shown in Fig. 5.

VI. CONCLUSIONS

Fano resonances occur very frequently in m esoscopic system s. Not much is known about scattering phase shifts for Fano resonances. We show that the three prong potential is a simple model that gives multichannelFano resonance. Unlike, previously studied potentials that show Fano resonances, this is an extended potential. In case of Fano resonances, scattering phase shifts in only some particular channels show sharp phase drops while others do not. The channels that do not show the

phase drops seem to be the more inform ative channels and hence very special channels. It seems that DOS is related to the scattering phase shifts of these special channels. As, this is exact for point scatterers, we were tem pted to check it for an extended scatterer that exhibit Fano resonance. The three prong potential studied show s that this is true when the Fano resonances are long lived. In all the experiments so far [9, 10, 11] one has encountered long lived Fano resonances where the phase drops are very sharp. As the life time of the resonances decrease, the energy derivative of the scattering phase shifts in these special channels and integrated charge inside the scatterer start deviating from each other. How ever, they are qualitatively sim ilar. The phase shift in the channels that exhibit the phase drops do not give any inform ation about the DOS, qualitatively or quantitatively, for long lived resonances or short lived resonances. So far, experim ents [9, 10, 11] and theories [8, 13] mostly focused on the phase shifts of these non-inform ative channels. We hope that this will give som e clues to future works to nd a m athem atical proof of this fact. Such a proof should be consistent with the features observed in the three prong potential and in the function potential in a quantum wire.

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Figure Captions

Fig. 1. A schematic diagram of the system studied. Three semi-in nite quantum wires meet at a point B. In the thin regions the quantum mechanical potential V is zero but in the thick regions it is not zero. The arrow shows the direction of propagation of an incident electron.

Fig. 2. arg (T_{13}) [solid curve] decreases sharply but continuously, when $J_{13}f$ [dotted curve] m in in izes. This is a signature of multichannel Fano resonance. 1 is the unit of length.

Fig. 3. $\arg(R_{11})$ [dotted curve] decreases sharply but continuously, when $\Re_{11}f$ [solid curve] m in in izes. This is a signature of multichannel Fano resonance. 1 is the unit of length.

Fig. 4. $\frac{d}{d(k_1)} \arg(T_{12})$ [solid curve] is positive everywhere, implying that there are no negative slopes in arg(T_{12}). $\frac{d}{d(k_1)} \arg(T_{12})$ [solid curve] and $\frac{d}{d(k_1)}$ [dotted curve] are very close to each other, in plying that arg(T_{12}) should carry all the information about DOS. Explicit calculations of ~v ^(W) (kl) [dashed] curve con msthis. 1 is the unit of length.

Fig. 5. Here we plot the same things as in Fig. 4. Di erence is that the resonances are short lived as compared to that in Fig. 4. The peaks in ~v $^{(N)}$ (kl) are broader sallow as compared to that in Fig. 4. $\frac{d}{d(kl)}arg(T_{12})$ is qualitatively similar to $\frac{d}{d(kl)}$ or ~v $^{(N)}$ (kl). There are quantitative di erences.

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